

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	394	257/197.ccls. and ((back or back side) with (gate or electrode or conductor or contact))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/07 10:31
L2	95	257/197.ccls. and ((back or backside) with (gate or electrode or conductor or contact))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/07 10:32
L3	55	257/565.ccls. and ((back or backside) with (electrode or gate))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/07 10:33
L4	55	(257/587 and 257/592).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/07 11:29
L5	203	(257/526).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/07 11:29
L6	330	semiconductor and SOI and ((back\$4 or buried) with (gate or electrode)) and inversion and (bipolar)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/07 11:51